## **Final report for**

## Symposium "Advanced Thermoelectrics: From Materials to Devices"

held at the E-MRS Spring 2013 conference, May 27-31, 2013, Strasbourg, France

#### Symposium organizers

Prof. Dr. Silke Bühler-Paschen Institute of Solid State Physics Vienna University of Technology Wiedner Hauptstr. 8-10 1040 Vienna Austria paschen@ifp.tuwien.ac.at

Dr. Sascha Populoh Laboratory for Solid State Chemistry and Catalysis Empa Ueberlandstrasse 129 8600 Duebendorf Switzerland

Jan D. König Fraunhofer Institute for Physical Measurements, IPM Heidenhofstr. 8 79110 Freiburg Germany

> Dr. Antonio Pereira Gonçalves Instituto Superior Técnico Universidade Técnica de Lisboa Estrada Nacional 10 2686-953 Sacavém Portugal

#### Summary

The development of advanced thermoelectric materials for efficient thermoelectric devices is a major challenge in energy conversion technologies. To overcome limitations of toxic and expensive state-ofthe-art bulk semiconductors, an improved fundamental understanding of the materials properties and of the thermoelectric conversion processes is needed. The aim of the symposium was to assemble scientists from universities, research institutes and industry to discuss recent discoveries in the field, and to promote co-operations on materials and devices. This goal was fully achieved as detailed in this report.



## Description of the scientific content and of discussions at the event

#### Introduction

The use of waste heat as energy source is an attractive and environmentally clean way to generate electrical power. With a thermoelectric (TE) device heat can be directly converted into electricity. TE devices work independently of mechanical and chemical conversion processes. Thus, they are emission free, silent, and extremely durable.

A conventional TE converter has an efficiency of 5-10%. It consists of numerous thermocouples, comprising *p*- and *n*-type thermoelements connected electrically in series and thermally in parallel. Heating one side of a thermoelectric material allows electrons and holes to thermally diffuse along the temperature gradient and to carry their charge with them. The amount of electrical power produced in this way depends on the thermoelectric conversion efficiency of the device and the heat flux. The relevant material parameters, i.e., the thermopower *S*, the electrical conductivity  $\sigma$ , and the thermal conductivity  $\kappa$ , are interrelated by the specific electronic structure of the material. This interrelation does usually not work in favour of high thermoelectric efficiencies. The dimensionless thermoelectric figure of merit

 $ZT = S^2 \sigma/\kappa T$ 

would, at a given temperature *T*, be maximized for materials with large thermopower, and high electrical but low thermal conductivity. In simple semiconductors, however, *S* is large when  $\sigma$  is small, and the electronic contribution to  $\kappa$  is directly related to  $\sigma$  via the Wiedemann-Franz law. To disentangle these properties, innovative materials design concepts are required, - and today increasingly explored by a highly active international scientific community.

Conventional TE devices as the ones used for space applications aim at high reliability, rather than high energy conversion efficiency or low cost. These devices are based on expensive and toxic materials (e.g. tellurides) and have low temperature stability when exposed to an oxidizing atmosphere. For future large-scale use, e.g. in the automotive sector, cheaper, more durable, and environmentally benign materials have to be found. To design better materials for future applications, a better understanding of the interplay of electronic and vibrational properties of solids is required. In parallel, materials engineering and device technology need to be advanced.

#### Organization

The symposium was organized in 12 scientifically coherent oral sessions (chronologically listed)

- Cage compounds
- Oxides
- Superlattices and membranes
- Tellurides
- Thermoelectric theory I
- Films, particles and quantum dots
- Nanowires and nanopillars
- Chalcogenides and intermetallics
- Devices and applications
- Novel thermoelectric materials
- Half-heuslers and silicides
- Thermoelectric theory II

plus two poster sessions, each introduced by flash presentations. The topic-wise grouping, which is not always done at similar events, helped to give a very good overview of the various subfields

of current worldwide research in thermoelectricity, and fostered discussions on the various subfields.

It was very fortunate that the coffee breaks were held directly in front of the lecture hall and that lunch was served at one single place (this is not always the case at E-MRS conferences!). Thus, discussions went on during the coffee breaks. In addition, most of the symposium attendees went to lunch (that was served at tables, no cueing...) together and continued intensive discussions there. This gave the symposium in fact very much the character of a workshop, with lots of informal exchange between the attendees!

Right from the beginning 0f the symposium, the organizers actively engaged the participants in discussions; lively discussions kept going on during the entire symposium - in particular also during the poster sessions.

There was a high involvement of young researchers and in particular of graduate students. Two graduate students received prices for their outstanding oral presentations. Also the two poster awards were given to excellent graduate students. The oral presentation awards were announced in the general E-MRS student award session, the poster awards (certificates plus small price money) were announced at the end of an oral session during the symposium.

#### **Scientific content**

The symposium covered the topic of thermoelectricity from a very broad perspective. Not only was the subtitle - from materials to devices - taken very literally, but also were other axes explored:

from simple model materials to materials of extreme complexity from plastics to borides from chemical to solid state synthesis from electrochemical thin film deposition to molecular beam epitaxy from nanoparticles to nanocomposites from lab-scale to large-scale materials fabrication from steady state to time resolved measurements from conventional thermoelectric concepts to entirely new approaches from phonon to electron engineering from molecular dynamics simulations to strongly correlated band theory from degradation to encapsulation from micro- to macro-devices

This breadth of topics made the symposium extremely inspiring.

Many outstanding talks with exciting results were presented. This short summary aims by no means at giving a full account of all the topics addressed and all results presented - it merely wants to give a flavour...

Many different materials classes were covered. Graphene, bismuth, silicon, bismuth tellurides and antimonides, lead tellurides, half-heusler compounds, oxides, chalcogenides, oxy-chalcogenides, borides, skutterudites, clathrates, complex Zintl compounds, Kondo insulators, topological insulators, organic conductors, glasses, phase change materials, CrN.

Most of these materials were studied as bulk single or polycrystals or as single or polycrystalline thick or thin films. Some of the materials were also investigated as nano- or microwires, nanosheets, or membranes.

While some participants focussed on the bare intrinsic materials properties, most presented optimization studies. Many different concepts (electron and phonon engineering) and techniques are explored to improve the thermoelectric efficiency of a given material, frequently leading to

interesting *ZT* values of the order of 1 to 1.5 in varying temperature ranges: doping/substitutions (up to pentenary compounds!), nanograin formation, phase separation, strain/shear, introduction of precipitates (including for instance  $C_{60}$ ), fabrication of composites, fabrication of ordered and even aperiodic heterostructures, superlattices and quantum dots, sometimes based on different isotopes different isotopes, ...

It becomes more and more common to study also the stability of the materials and in particular of their artificial nano/microstructuring upon thermal cycling. However, real long term studies have not been presented. Instead, many different strategies are explored to stabilize the structures.

On the characterization side, the spectrum has broadened considerably. While the standard steady state techniques to measure the thermoelectric quantities of bulk samples are still broadly used, alternative technique are getting more widespread, e.g., scanning thermal probe micro-imaging, the 3 omega technique, laser flash diffusivity measurements, time domain thermal reflectance, pump-probe techniques, Raman thermometry, ...

Many presentations also dealt with the fabrication of devices. The progress on microgenerators, frequently based on nanostructures, is impressive. Also a number of traditional thermoelectric generators, fabricated typically from compacted and sintered powders, were presented. It is unfortunate that open discussion on the science of contacting is very rare. This clearly slows down the progress of this technologically highly relevant issue. Some presentations also addressed upscaling. A number of research institutes collaborate with industry on pilot materials powder production plants. Also the integration of thermoelectric modules into automobiles and roadmaps to the targeted efficiencies and costs levels were discussed.

Finally, also entirely new approaches to explore thermoelectric effects for energy generation were discussed, e.g., pn junction thermoelectric generators, thermionic converters, spin Seebeck plus spin Hall effect generators, and liquid chemical thermocouples.

And finally, just a few highlights: A new world record in thermoelectric efficiency of clathrates over the relevant temperature range was shown. An entirely new thermolectric device concept based on spin current plus spin Hall effect was presented and realized in a microgenerator. The simultaneous drastic enhancement of the electrical conductivity and the thermopower in halfheusler compounds by certain additives was demonstrated.

#### Scientific committee

Fairbanks, John W.; DOE, USA Grin, Juri; Dresden, Germany Hebert, Sylvie; Caen, France (f) Nielsch, Kornelius; Hamburg, Germany Schierle-Arndt, Kerstin; BASF AG, Germany (f) Tobola, Janusz; Krakow, Poland

#### **Conference Proceedings**

All participants were strongly encouraged to submit a manuscript to the journal *physica status solidi (a)* that will publish a special issue of fully peer reviewed papers as conference proceedings.

#### Information on the budget

As detailed in the table below, the INTELBIOMAT funding was used to partly cover the conference fees and/or travel costs and/or accommodation costs of invited speakers from Europe, one invited speaker from Korea and the conference organizers. In addition a discussion dinner to which all

invited speakers and committee members were invited was funded. Three best paper awards will be given after all referee reports of the proceedings papers (see above) are received. The selection will be done by the symposium organizers, taking the reviewer's comments into account. No price will go the the organizers' groups. Focus will be on contributions from young scientists and/or scientists from emerging countries. A lump sum of 700 EUR (< 10 % of total ESF funding) covers the administrative costs.

	Total	Conf. fee Other	Price costs	Admin.	Meals	Accomm	Travel
Total ESF awarded	7800€						
Organizers							
Silke Bühler-Paschen	999,71€					647,50€	352,21 €
Sascha Populoh	472,66 €					391,00€	81,66 €
Antonio Pereira G.	567,29€					248,00€	319,29€
Jan D. König	391,72€					331,50€	60,22€
Speakers							
Kaczorowski Dariusz	560€	560 €					
Lechermann Frank	640€	640 €					
Schierning Gabi	640€	640 €					
Rogl Peter	640€	640 €					
Wooyoung Lee	640€	640€					
Conference Dinner	540€				540€		
Best paper 1.	500€		500€				
Best paper 2.	300€		300€				
Best paper 3.	200€		200€				
Administrative costs	700€			700€			
Total ESF spent	7791,38€	3120 € 4120,	1000 € ,00 €	700€	540 €	1618,00 €	813,38 €
Balance	8,62€						

Details on the budget are also given in the web-form. All receipts are available on request.

#### Acknowledgments during the symposium

The generous funding of INTELBIOMAT was acknowledged on a dedicated slide presented in the conference hall whenever no presentation was projected. In addition the Chair of the conference mentioned INTELBIOMAT funding in her closing comments. INTELBIOMAT will also be acknowledged in the conference proceedings.

# Assessment of the results and impact of the event on the future directions of the field

The symposium was a testimony of great worldwide activity in the field of advanced thermoelectrics. A wast amount of different subtopics are addressed by a broad community. The results are getting more reliable and reproducible, application relevant issues are considered by an increasing number of scientists. Overall, there is hope in the community that thermoelectric applications in waste heat generation will not remain a dream.

The symposium participants came from 21 countries.

The large percentage of non-Europeans points to the high standing of the European thermoelectrics community, but also to the need to form stronger networks within Europe to be able to compete in this challenging field.

## Annexes: Programme of the meeting and full list of speakers and participants

#### List of invited speakers

Felser, Claudia; Max Planck Institute for Chemical Physics of Solids, Germany (f) Heremans, Joseph; Ohio State University, USA Kaczorowski, Darius; Inst. Low Temp. Structure Research, Poland Lechermann, Frank; Hamburg University, Germany Lee, Wooyoung; Yonsei University, Korea Meisner, Gregory, GM Moters, USA Nolas, George; Univ. South Florida, USA Prellier,Wilfried, Caen, France Rogl, Peter, Vienna University, Austria Schierning, Gabi; Duisburg-Essen University, Germany (f) Snyder, Jeff, Caltech, USA Zhifeng, Ren; Houston University, USA

#### **Full list of participants**

Peter	ROGL	University of Vienna
Hiroaki	ANNO	Tokyo University of Science, Yamaguchi
Wilfried	Prellier	CNRS/ENSICAEN
worawut	KHUNSIN	catalan institute of nanotechnology
Francois	MORINI	Institut Electronique Microelectronique Nanotechnologies
Matthias	SCHRADE	University of Oslo
Wonchul	CHOI	KAIST
Soizic	EON	WWU Münster
Markus	WINKLER	Fraunhofer Institute for Physical Measurement Techniques IPM
Sebastian	REPARAZ	Catalan Institute of Nanotechnology
Daniel	GRIMM	TU Chemnitz
Markus R.	Wagner	Catalan Institute of Nanotechnology (ICN)
Davide	BERETTA	Istituto Italiano di Tecnologia
Kyung Tae	KIM	Korea Institute of Materials Science
Xinlin	YAN	Institute of Solid State Physics
Viskadouraki		
S	ZACHARIAS	FORTH
Danila	Ovsyannikov PEREIRA	TISNCM
Antonio	GONÇALVES	IST/ITN, Instituto Superior Técnico, UTL
Gilgeun	LEE	Pukyong National University
Dimitrios	CHALIAMPALIAS	Aristotle University of Thessaloniki
Krzysztof	DYBKO	Polish Academy of Sciences
Soufiene	ILAHI	université of carthage
Nikolaeva	ALBINA	Gitsu IIEN
Anderson	Dussan	Universidad Nacional de Colombia - Dpto. Física
Seungwoo	HAN	Korea Institute of Machinery and Materials
Nikolaeva	ALBINA	Gitsu IIEN
Gyeong Ock	PARK	Yonsei University, Korea
Nicola	PERANIO	University of Tuebingen
Jonathan	HAENEL	Vienna University of Technology

Leonid	KONOPKO	Ghitu Institute of Electronic Engineering and Nanotechnologies
Fredy	Mesa	Unversidad Libre de Colombia
GLORIA	VILARDELL	LEITAT TECHNOLOGICAL CENTER
Helmut	BAUMGART	Old Dominion University
Helmut	BAUMGART	Dominion University
George	NOLAS	University of South Florida
Biplab	PAUL	Linköping University (Sweden)
Andreas	SCHMITZ	German Aerospace Center (DLR)
Michal	SZOT	Polish Academy of Sciences
Jean-	0201	
Baptiste	VANEY	Institut Jean Lamour, Nancy, France
Matthias	WUTTIG	RWTH Aachen
Joseph	P. HEREMANS	The Ohio State University
Roberto	DAGOSTA	Universidad del Pais Vasco
Rafael	Frieling	University of Münster
SIT		Linköning Universitiv
Kamil		Akademia Córniczo Hutnicza im Stanisł awa Staszica w Krakowie
Zhifong	DENI	University of Houston
Zimeny		Cormon Acroonage Conter (DLD)
Jayaram		Jenen Advanged Institute of Science and Technology
IVIAI mahain		Japan Advanced Institute of Science and Technology
	SALEEIVII	
Hanns-Uirich	Habermeier	
Dario		
Hung-vvei	Isal	National Ising Hua University
Noriyuki	UCHIDA	AISI
etienne	DRAHI	emse/cmp
Anil	KUAMR	National Physical Laboratory New Delhi
Wooyoung	LEE	Yonsei University
Gabi	SCHIERNING	University of Duisburg-Essen
Wang	CHING-CHI	National Central University
Jeongmin	KIM	Yonsei University, Korea
Jae Yong	SONG	Korea Research Institute of Science and Technology
XANTHIPPI	ZIANNI	TECHNOLOGICAL EDUCATIONAL INSTITUTION OF CHALKIDA
Alexey	ZOZULYA	DESY
Claudia	FELSER	Max Planck Institute
Céline	BARRETEAU	Université Paris-Sud 11
Michihiro	OHTA	National Institute of Advanced Industrial Science and Technology (AIST)
Maik	WAGNER-REETZ	Max-Planck-Institute for Chemical Physics of Solids
Anna	SEMENOVA SCHWINGENSCH	Institute of Solid State Chemistry
Udo	LOGL	KAUST
Sergei	VASSEL	Rostov branch of MGUTU
MASAMI	MORI	Chubu Electric Power Co., Inc.
Soufiene	ILAHI	université of carthage
Laurie	WINKLESS	National Physical Laboratory
Alex	POKROPIVNY	UPR CNRS 288 Ecole Centrale Paris
Shaolin	Zhang	Yonsei University
lgor	VEREMCHUK	Max-Planck-Institut für Chemische Physik fester Stoffe
Gregor	KIESLICH	Johannes Gutenberg-Universität Mainz
Ta-Lei	CHOU	Aalto University

Sascha	POPULOH	Empa
Gesine	Saucke	Empa
Leyre	SAGARNA RODRÍGUEZ-	Empa
Javier	VIEJO	Universitat Autònoma de Barcelona
Alex	POKROPIVNY	UPR CNRS 288 Ecole Centrale Paris
Gregory	MEISNER	GM Global Research and Development
Matthias	FEINAEUGLE	University of Southampton
Jana	HEUER	Fraunhofer IPM
Seungwoo	HAN RODRÍGUEZ-	Korea Institute of Machinery and Materials
Javier	VIEJO	Universitat Autònoma de Barcelona
Raimar	ROSTEK	University of Freiburg
Jeff	SNYDER	Caltech
Alejandro R.	GOÑI	ICMAB-CSIC
Masatoshi	TAKEDA	Nagaoka University of Technology
Francisco	RIVADULLA	Universidad de Santiago de Compostela
Akihiro	KIRIHARA	NEC Corporation
		Institute of Low Temperature and Structure Research, Polish Academy of
Dariusz	KACZOROWSKI	Sciences
Krzysztof	Galazka	University of Bern
WENJIE	XIE	Empa
Titas	DASGUPTA	German Aerospace Center
Philippe	BELLANGER BERNARD-	ICMCB
Guillaume	GRANGER	CEA
Frank	LECHERMANN	University of Hamburg
Yong-Sung	KIM MURPHY	Korea Research Institute of Standards and Science
Felipe	ARMANDO	University College Cork
Alex	POKROPIVNY	UPR CNRS 288 Ecole Centrale Paris
Shiyun	XIONG	Ecole Centrale Paris

### Final programme of the meeting

The final programme of the meeting is given in the table below. Invited talks are highlighted in green. Talks/posters that were canceled and other are indicated.

ΤΥΡΕ	REF	DATE	HOUR	TITLE	NAME	FIRSTNAME
		27-05- 2013	09:00	Welcome	Bühler- Paschen	Silke
SESSION		Cage Con	npounds	s : Silke Bühler-Paschen		
invited	C.I-1	27-05- 2013	09:15	Thermoelectric Functions in Intermetallic Clathrates	ROGL	Peter
oral	C.I-2	27-05- 2013	09:45	Thermal stablity and oxidation resistance of polycrystalline Ba8Al16Si30-based clathrates	ANNO	Hiroaki
oral	C.I-3	27-05- 2013	10:00	Iron doping of skuttedudites via chemical synthesis - Changed to poster, session C.PI	YAKHSHI TAFTI	Mohsen
BREAK		27-05- 2013		Coffee Break		
SESSION		Oxides : 2	Zhifeng	Ren		
invited	C.II-1	27-05- 2013	10:45	Thermoelectric materials from Bulk to thin films	Prellier	
oral	C.II-2	27-05- 2013	11:15	Strong thickness-dependent and large thermoelectric effect in lightly doped Nb:SrTiO3 thin films	KHUNSIN	worawut
oral	C.II-3	27-05- 2013	11:30	Thermoelectric properties of epitaxial LiCoO2 thin films- <b>REMOVED</b>	MIHAILESC U	Nicolae Cristian
oral	C.II-4	27-05- 2013	11:45	Low work function thin film growth for high efficiency thermionic energy converter: coupled Kelvin probe and photoemission study of potassium oxide	MORINI	Francois
oral	C.II-5	27-05- 2013	12:00	Effect of oxygen content on the thermoelectric properties of CaMnO3-x	SCHRADE	Matthias
BREAK		27-05- 2013		Lunch		
SESSION		Su	perlattio	ces & Membranes : Hanns-Ulrich Habermeier		
invited	C.III- 1	27-05- 2013	14:00	High-Temperature Power Generation Devices from Nanostructured Half-Heusler Materials	Ren for D'ANGELO	Jonathan
oral	C.III- 2	27-05- 2013	14:30	Thermoelectric effect of silicide and silicon hetero-junction structured devices	СНОІ	Wonchul
oral	C.III- 3	27-05- 2013	14:45	Thermal conductivity of periodic and aperiodic silicon isotope structures	EON	Soizic
oral	C.III- 4	27-05- 2013	15:00	New results on Bi2Te3/Sb2Te3 – related superlattices grown with molecular beam epitaxy (MBE) and nanoalloying	WINKLER	Markus
oral	C.III-	27-05-	15:15	Determination of the thermal conductivity of Si and Ge thin membranes through	REPARAZ	Sebastian

	5	2013		Raman thermometry.		
oral	C.III- 6	27-05- 2013	15:30	Thermal conductivity in nanomembrane hybrid superlattices	GRIMM	Daniel
oral	C.III- 7	27-05- 2013	15:45	Acoustic phonon dynamics in free-standing silicon and germanium membranes	Wagner	Markus R.
SESSION		Ро	sters-I :	Sascha Populoh		
Flash post	er pres	entations	16:00		all	
poster	C.PI- 1	27-05- 2013	16:00	Thermoelectric Properties of Organic Conductors	BERETTA	Davide
poster	C.PI- 2	27-05- 2013	16:00	Thermoelectric Properties of p-type Bi2Te3 Thick-Film Processed by a Screen Printing Process <b>NOT PRESENTED</b>	KIM	Kyung Tae
poster	C.PI- 3	27-05- 2013	16:00	Effect of process parameters for ball milling and hot pressing on the thermoelectric properties of type I clathrates	YAN	Xinlin
poster	C.PI- 4	27-05- 2013	16:00	Transport Properties of lightly doped La(1-x)Sr(x)CoO(3) thin films	ZACHARIAS	Viskadourakis
poster	C.PI- 5	27-05- 2013	16:00	C60-doping of nanostructured thermoelectric.	Ovsyanniko v	Danila
poster	C.Pl- 6	27-05- 2013	16:00	Recent Advances on Thermoelectric Glasses	PEREIRA GONÇALVE S	Antonio
poster	C.PI- 7	27-05- 2013	16:00	Thermoelectric properties of Bi0.5Sb1.5Te3 fabricated by mechanical milling and spark plasma sintering processes	LEE	Gilgeun
poster	C.PI- 8	27-05- 2013	16:00	Thermoelectric properties of Bi0.5Sb1.5Te3 powder synthesized using metallic salts	LEE	Gilgeun
poster	C.PI- 9	27-05- 2013	16:00	Thermoelectric properties of Mg2Si coatings deposited by pack cementation process on heavily doped Si substrates	CHALIAMPA LIAS	Dimitrios
poster	C.PI- 10	27-05- 2013	16:00	On the Effect of Ge on the Mg2Si1-x-ySnxGey Materials- <b>REMOVED</b>	KYRATSI	Theodora
poster	C.PI- 11	27-05- 2013	16:00	Thermoelectric Properties of Hot-Pressed β,-K2Bi8-xSbxSe13 Materials- REMOVED	KYRATSI	Theodora
poster	C.PI- 12	27-05- 2013	16:00	Thermoelectric performance of n-type and p-type Pb_(1-x)Mn_(x)Te (x=0.05) bulk crystals	DYBKO	Krzysztof
poster	C.PI- 13	27-05- 2013	16:00	Boron effects on optical and thermal properties of BGaAs/GaAs alloys <b>NOT PRESENTED</b>	ILAHI	Soufiene
poster	C.PI- 14	27-05- 2013	16:00	GALVANOMAGNETIC AND THERMOELECTRIC PROPERTIES OF TE DOPED SINGLE- CRYSTAL BISMUTH WIRES AND FILMS <b>NOT PRESENTED</b>	ALBINA	Nikolaeva

poster	C.PI- 15	27-05- 2013	16:00	Influence of the doping profile and trap levels in thin films Si from the evaluation of thermally stimulated current <b>NOT PRESENTED</b>	Dussan	Anderson
poster	C.PI- 16	27-05- 2013	16:00	High-temperature thermoelectric properties of Zn-Sb thin films deposited by co- sputtering	HAN	Seungwoo
poster	C.PI- 17	27-05- 2013	16:00	TEMPERATURE AND MAGNETIC DEPENDENCES THE RESISTANCE AND THERMOPOWER IN A TOPOLOGICAL INSULATOR Bi1-xSbx WIRES	ALBINA	Nikolaeva
poster	C.PI- 18	27-05- 2013	16:00	Novel Thermoelectric PEDOT:PSS/Ge composites	PARK	Gyeong Ock
poster	C.PI- 19	27-05- 2013	16:00	Control of stoichiometry in Bi2Te3 based nanomaterials	PERANIO	Nicola
poster	C.PI- 20	27-05- 2013	16:00	Thermoelectric properties of the anisotropic Kondo insulator CeRu4Sn6	HAENEL	Jonathan
poster	C.PI- 21	27-05- 2013	16:00	Thermoelectric properties of Bi2Te3 microwires	копорко	Leonid
poster	C.PI- 22	27-05- 2013	16:00	Growth and structural characterization of Cu2ZnSnSe4 thin films used in solar cells <b>NOT PRESENTED</b>	Mesa	Fredy
poster	C.PI- 23	27-05- 2013	16:00	NANOCOMPOSITES WITH INSTRINSICALLY CONDUCTING POLYMERS FOR THERMOELECTRIC APPLICATIONS <b>NOT PRESENTED</b>	VILARDELL	GLORIA
poster	C.PI- 24	27-05- 2013	16:00	ALD Growth of PbTe Thin Films for Thermoelectric Applications	BAUMGART	Helmut
poster	C.PI- 25	27-05- 2013	16:00	TEM Investigation of Bi2Te3/Sb2Te3 Nanolaminate Structures Synthesized by Atomic Layer Deposition	BAUMGART	Helmut

SESSION		Tellurides : l	Peter Rogl			
invited	C.IV-1	28-05-2013	08:30	Thermoelectric research for automobile applications: An experimental and computational approach to materials and interfaces.	NOLAS	George
oral	C.IV-2	28-05-2013	09:00	Compensation of excess carrier concentration by impurity levels: an alternative approach for higher thermoelectric efficiency	PAUL	Biplab
oral	C.IV-3	28-05-2013	09:15	Increasing the mechanical stability of lead telluride by alloying with non-doping elements	SCHMITZ	Andreas
oral	C.IV-4	28-05-2013	09:30	Thermal and thermoelectric properties of Pb_1- $xCd_xTe (x=0-0.11)$ solid solutions	SZOT	Michal
oral	C.IV-5	28-05-2013	09:45	Cu-As-Te glassy systems: challenges and prospects for thermoelectric applications.	VANEY	Jean-Baptiste
oral	C.IV-6	28-05-2013	10:00	Disorder Induced Suppression of Lattice Heat Conduction in Crystalline Chalcogenides with thermoelectric properties	WUTTIG	Matthias
BREAK		28-05-2013		Coffee Break		
SESSION		Thermoelect	tric Theory - I	: Janusz Tobola		
invited	C.V-1	28-05-2013	10:45	Resonant levels in bulk thermoelectric semiconductors	P. HEREMANS	Joseph
oral	C.V-2	28-05-2013	11:15	Thermoelectric efficiency in Si and Ge nanoribbons	DAGOSTA	Roberto
oral	C.V-3	28-05-2013	11:30	Molecular dynamics calculations of the thermal conductivity of isotopically modulated silicon multilayer nanowires	Frieling	Rafael
oral	C.V-4	28-05-2013	11:45	First principle calculations of alloy phase stability of ScN-based materials for thermoelectric application	KERDSONGPANY A	SIT
oral	C.V-5	28-05-2013	12:00	Boltzmann transport and electronic structure calculations in disordered thermoelectrics: application to Ti(Fe-Ni)Sb half-Heusler alloys	KUTORASINSKI	Kamil
BREAK		28-05-2013		Lunch		
SESSION		Nanostructu	red Bulk Mate	rials : George Nolas		
invited	C.VI-1	28-05-2013	14:00	Nanostructured Bulk Thermoelectric Materials	REN	Zhifeng
oral	C.VI-2	28-05-2013	14:30	Evolution of phase segregation and spinodal structures in the AgPb18SbTe20 system during melt	DADDA	Jayaram

				synthesis and thermoelectric properties of Ag1- yPb18Sb1+zTe20 compounds		
oral	C.VI-3	28-05-2013	14:45	Novel Synthetic Process and Enhanced Thermoelectric Properties of CNT/Bi2Te3 Nanocomposites- <b>REMOVED</b>	КІМ	Kyung Tae
oral	C.VI-4	28-05-2013	15:00	ZnSb Nanoparticles and Nanostructured Materials: Chemical Synthesis, Characterization and Thermoelectric Properties	NGUYEN THANH	Mai
oral	C.VI-5	28-05-2013	15:15	Antimony as an additional n-type dopant in nanosilicon <b>NOT PRESENTED</b>	PETERMANN	Nils
oral	C.VI-6	28-05-2013	15:30	Chemical synthesis and thermoelectric evaluation of nanostructured iron antimonide (FeSbx) - Changed to poster, session C.PI	SALEEMI	Mohsin
oral	C.VI-7	28-05-2013	15:45	Interface crystallization and thermoelectric performance of n-type Bi2(Te/Se)3 nanoplatelet composites <b>NOT PRESENTED</b>	XIONG	Qihua
BREAK		28-05-2013		Coffee Break		
				Data dan Kinin		
SESSION		Films, Particle	s & Quantum	Dots : Jan Konig		
<b>SESSION</b> oral	C.VII-1	28-05-2013	16:30	Te concentration and thickness dependence on the thermoelectric properties of p-type Bi0.5Sb1.5Te3+X thin films deposited by Pulsed Laser Deposition - <b>REMOVED</b>	ATHANASOPOUL OS	Georgios
SESSION oral invited	C.VII-1 C.VII-8	28-05-2013 28-05-2013	16:30 <b>16:15</b>	Te concentration and thickness dependence on the thermoelectric properties of p-type Bi0.5Sb1.5Te3+X thin films deposited by Pulsed Laser Deposition - <b>REMOVED</b> How to Make That Breakthrough in Energy Conversion: Thermoelectricity	ATHANASOPOUL OS LEE	Georgios Wooyoung
session oral invited oral	C.VII-1 C.VII-8 C.VII-2	28-05-2013 28-05-2013 28-05-2013	16:30 <b>16:15</b> 16:45	Te concentration and thickness dependence on the thermoelectric properties of p-type Bi0.5Sb1.5Te3+X thin films deposited by Pulsed Laser Deposition - <b>REMOVED</b> How to Make That Breakthrough in Energy Conversion: Thermoelectricity Thickness dependence and giant high temperature thermoelectric response of Ca3Co4O9 thin films	ATHANASOPOUL OS LEE Habermeier	Georgios Wooyoung Hanns-Ulrich
session oral invited oral oral	C.VII-1 C.VII-8 C.VII-2 C.VII-3	28-05-2013 28-05-2013 28-05-2013 28-05-2013	16:30 16:15 16:45 17:00	Te concentration and thickness dependence on the thermoelectric properties of p-type Bi0.5Sb1.5Te3+X thin films deposited by Pulsed Laser Deposition - <b>REMOVED</b> How to Make That Breakthrough in Energy Conversion: Thermoelectricity Thickness dependence and giant high temperature thermoelectric response of Ca3Co4O9 thin films Enhancement of the Power Factor in Two-Phase Silicon-Boron Nanocrystalline Alloys	ATHANASOPOUL OS LEE Habermeier	Georgios Wooyoung Hanns-Ulrich Dario
SESSION oral oral oral oral	C.VII-1 C.VII-8 C.VII-2 C.VII-3 C.VII-4	28-05-2013 28-05-2013 28-05-2013 28-05-2013 28-05-2013	16:30 16:15 16:45 17:00 17:15	Te concentration and thickness dependence on the thermoelectric properties of p-type Bi0.5Sb1.5Te3+X thin films deposited by Pulsed Laser Deposition - <b>REMOVED</b> How to Make That Breakthrough in Energy Conversion: Thermoelectricity Thickness dependence and giant high temperature thermoelectric response of Ca3Co4O9 thin films Enhancement of the Power Factor in Two-Phase Silicon-Boron Nanocrystalline Alloys Fabrication of large scale single crystal Bi2Te3 nanosheet arrays via one-step electrolysis process	ATHANASOPOUL OS LEE Habermeier NARDUCCI Tsai	Georgios Wooyoung Hanns-Ulrich Dario Hung-Wei
SESSION oral invited oral oral oral oral	C.VII-1 C.VII-8 C.VII-2 C.VII-3 C.VII-4	28-05-2013 28-05-2013 28-05-2013 28-05-2013 28-05-2013 28-05-2013	16:30 16:15 16:45 17:00 17:15 17:30	Te concentration and thickness dependence on the thermoelectric properties of p-type Bi0.5Sb1.5Te3+X thin films deposited by Pulsed Laser Deposition - <b>REMOVED</b> How to Make That Breakthrough in Energy Conversion: Thermoelectricity Thickness dependence and giant high temperature thermoelectric response of Ca3Co4O9 thin films Enhancement of the Power Factor in Two-Phase Silicon-Boron Nanocrystalline Alloys Fabrication of large scale single crystal Bi2Te3 nanosheet arrays via one-step electrolysis process Seebeck effects of silicon and nickel silicide nanocrystals composite films	ATHANASOPOUL OS LEE Habermeier NARDUCCI Tsai UCHIDA	Georgios Wooyoung Hanns-Ulrich Dario Hung-Wei Noriyuki
SESSION oral invited oral oral oral oral oral	C.VII-1 C.VII-8 C.VII-2 C.VII-3 C.VII-5 C.VII-6	28-05-2013   28-05-2013   28-05-2013   28-05-2013   28-05-2013   28-05-2013   28-05-2013   28-05-2013   28-05-2013   28-05-2013	16:30 16:15 16:45 17:00 17:15 17:30 17:45	Dots : Jan KonigTe concentration and thickness dependence on the thermoelectric properties of p-type Bi0.5Sb1.5Te3+X thin films deposited by Pulsed Laser Deposition - <b>REMOVED</b> How to Make That Breakthrough in Energy Conversion: ThermoelectricityThickness dependence and giant high temperature thermoelectric response of Ca3Co4O9 thin filmsEnhancement of the Power Factor in Two-Phase Silicon-Boron Nanocrystalline AlloysFabrication of large scale single crystal Bi2Te3 nanosheet arrays via one-step electrolysis processSeebeck effects of silicon and nickel silicide nanocrystals composite filmsSintering of Inkjet-printed Silicon Nanoparticles for Thermoelectric Devices	ATHANASOPOUL SS LEE Habermeier NARDUCCI Sai UCHIDA	Georgios Wooyoung Hanns-Ulrich Dario Hung-Wei Noriyuki etienne

SESSION		Nanowires & I	Vanopillars : C	laudia Felser		
invited	C.VIII- 1	29-05-2013	08:30	Nanostructured bulk silicon for thermoelectricity: A model system to explore novel device concepts	SCHIERNING	Gabi
oral	C.VIII- 2	29-05-2013	09:00	Thermoelectric properties of nano-scale Si1-xGex pillars array and microcooling devices	CHING-CHI	Wang
oral	C.VIII- 3	29-05-2013	09:15	Thermoelectric Property of Nanostructure- Engineered Bi-Te Core/shell Nanowire Grown by On- Film Formation of Nanowires	KIM	Jeongmin
oral	C.VIII- 4	29-05-2013	09:30	Thermoelectric measurement of single nanowire using a microfabricated platform	SONG	Jae Yong
oral	C.VIII- 5	29-05-2013	09:45	Optimization prospects for geometry-modulated nanowires against their thermoelectric efficiency	ZIANNI	XANTHIPPI
oral	C.VIII- 6	29-05-2013	10:00	Coherent x-ray diffraction study of GaAs nanopillars embedded in air-gap heterostructures	ZOZULYA	Alexey
BREAK		29-05-2013		Coffee Break		
SESSION		Chalcogenide	s & Intermeta	llics : Dariusz Kaczorowski		
invited	C.IX-1	29-05-2013	10:45	Topological insulators and thermoelectric materials	FELSER	Claudia
oral	C.IX-2	29-05-2013	11:15	Layered oxychalcogenides: new high-ZT thermoelectric materials	BARRETEAU	Céline
oral	C.IX-3	29-05-2013	11:30	Thermoelectric Properties of TS2 (T: Ti, Cr) Based Layer Sulfides Prepared by CS2 Sulfurization	OHTA	Michihiro
oral	C.IX-4	29-05-2013	11:45	Thermoelectric Properties of Layered Antiferromagnetic CuCrSe2 <b>NOT PRESENTED</b>	TEWARI	GIRISH C
oral	C.IX-5	29-05-2013	12:00	Tuning of the thermoelectric properties of intermetallic phases Ru1-xTxIn3 (T = Re, Rh, Ir) by electron and phonon engineering	WAGNER-REETZ	Maik
BREAK		29-05-2013		Lunch		
SESSION		Posters-II : Al	ntónio Pereira	Gonçalves		
Flash poster pr	resentati	ons	14:00		all	
poster	C.PII-1	29-05-2013	14:00	LixNayCoO2 as promising thermoelectric material: synthesis, structure, properties.	SEMENOVA	Anna
poster	C.PII-2	29-05-2013	14:00	Anomalous enhancement of the thermoelectric figure of merit by V co-doping in SrTiO3	SCHWINGENSCHL OGL	Udo

poster	C.PII-3	29-05-2013	14:00	CHEMICAL THERMOCOUPLE AS EFFECTIVE DEVICE FOR CONVERTING HEAT INTU ELECTRICITY IN LOW TEMPERATURE GRADIENTS	VASSEL	Sergei
poster	C.PII-4	29-05-2013	14:00	First principles calculation of Seebeck coefficients of α,-FeO(OH)	MORI	MASAMI
poster	C.PII-5	29-05-2013	14:00	Two-layer photo-thermal deflection model to study the non-radiative recombination process: Application to Ga0.7In0.3Al0.23As0.77/GaSb and Al0.3Ga0.7As0.08Sb0.92/GaSb laser structures <b>NOT</b> <b>PRESENTED</b>	ILAHI	Soufiene
poster	C.PII-6	29-05-2013	14:00	Reliable Characterisation of Thermoelectric Generators <b>NOT PRESENTED</b>	WINKLESS	Laurie
poster	C.PII-7	29-05-2013	14:00	Computational studies of vacancies, antisite, and exchange pairs defects in bismuth telluride <b>NOT</b>	Pokropivny	Alex
poster	C.PII-8	29-05-2013	14:00	Effect of transition metals doping on the thermoelectric properties of Zn1-xAlxO	Zhang	Shaolin
poster	C.PII-9	29-05-2013	14:00	Spark plasma preparation of Ti1-xVxO1.9 (x = $0 \div 0.1$ ) and their thermoelectric properties	VEREMCHUK	lgor
poster	C.PII- 10	29-05-2013	14:00	Using Crystallographic Shear to Reduce Lattice Thermal Conductivity: Magn?li Oxides for Thermoelectric Application	KIESLICH	Gregor
poster	C.PII- 11	29-05-2013	14:00	Misfit-layered cobalt oxides by hydrothermal synthesis	CHOU	Ta-Lei
poster	C.PII- 12	29-05-2013	14:00	Correlated transition metal oxides for thermoelectric power generation	POPULOH	Sascha
poster	C.PII- 13	29-05-2013	14:00	Oxide thermoelectric converters for waste heat recovery designed by applying the compatibility approach	Saucke	Gesine
poster	C.PII- 14	29-05-2013	14:00	Partial nitrogen substitution in thermoelectric EuTiO3	SAGARNA	Leyre
poster	C.PII- 15	29-05-2013	14:00	Thermal conductivity in compositionally-graded Si1- xGex superlattices	RODRÍGUEZ- VIEJO	Javier
poster	C.PII- 16	29-05-2013	14:00	First-principle simulation of atomically-thin films and nanotubes of bismuth telluride <b>NOT PRESENTED</b>	POKROPIVNY	Alex
poster	C.PII- 17	29-05-2013	14:00	Tailoring properties of graphene with vacancies <b>NOT PRESENTED</b>	POKROPIVNY	Alex

SESSION		Devices & Ap	plications : Jol	nn Stockholm		
invited	C.X-1	30-05-2013	08:30	Thermoelectric Generators for Direct Conversion of Automotive Waste Heat into Useful Electrical Power	MEISNER	Gregory
oral	C.X-2	30-05-2013	09:00	Laser-assisted direct writing of thermoelectric generators	FEINAEUGLE	Matthias
oral	C.X-3	30-05-2013	09:15	Development of Skutterudite Thermoelectric Modules	HEUER	Jana
oral	C.X-4	30-05-2013	09:30	Performance evaluation of solar thermoelectric generator	HAN	Seungwoo
oral	C.X-5	30-05-2013	09:45	CMOS compatible planar thermoelectric microgenerator based on top-down Si nanowires	RODRÍGUEZ- VIEJO	Javier
oral	C.X-6	30-05-2013	10:00	Electrochemical Fabrication and Characterization of Thermoelectric Micro Generators	ROSTEK	Raimar
BREAK		30-05-2013		Coffee Break		
SESSION		Novel Thermo	pelectric Mater	rials : Gregory Meisner		
invited	C.XI-1	30-05-2013	10:45	Complex Zintl Compounds for Discovering new High Efficiency Thermoelectric Materials	SNYDER	Jeff
oral	C.XI-2	30-05-2013	11:15	Poly(3-hexylthiophene)-carbon nanotube composites for high-performance organic thermoelectrics	GOÑI	Alejandro R.
oral	C.XI-3	30-05-2013	11:30	Synthesis and Thermoelectric Properties of p-type Hexaborides	TAKEDA	Masatoshi
oral	C.XI-4	30-05-2013	11:45	Thermoelectric properties of CrN	RIVADULLA	Francisco
oral	C.XI-5	30-05-2013	12:00	Novel thermoelectric sheets based on the spin Seebeck effect	KIRIHARA	Akihiro
BREAK		30-05-2013		Lunch		
SESSION		Half-Heusler	& Silicides : Je	ff Snyder		
invited	C.XII-1	30-05-2013	14:00	Rare-earth-based half-Heusler phases for thermoelectric applications	KACZOROWSKI	Dariusz
oral	C.XII-2	30-05-2013	14:30	Phase stability and oxidation studies of (Ti0.33Zr0.33Hf0.33)NiSn half-Heusler compounds	Gał,ą ,zka	Krzysztof
oral	C.XII-3	30-05-2013	14:45	Significant ZT Enhancement in half-Heusler Nanocomposites via a Synergistic 'High Mobility Electron Injection, Energy filtering and Boundary Scattering' Approach	XIE	WENJIE

oral	C.XII-4	30-05-2013	15:00	Influence of power factor enhancement on the thermoelectric figure of merit in Mg2Si0.4Sn0.6 based materials	DASGUPTA	Titas
oral	C.XII-5	30-05-2013	15:15	Nanostructure stability and thermoelectric properties of Mg2(Si,Sn) thermoelectric material	BELLANGER	Philippe
oral	C.XII-6	30-05-2013	15:30	Microstructure ? thermoelectrical properties relationships for a n-type polycrystalline Si1-xGex alloy sintered by SPS	BELLANGER for BERNARD- GRANGER	Guillaume
oral	C.XII-7	30-05-2013	15:45	Thermoelectric properties of doped Mg2Si1-x- ySnxGey Solid Solutions- <b>REMOVED</b>	KYRATSI	Theodora
BREAK		30-05-2013		Coffee Break		
SESSION	Thermoelectric Theory - II : Joseph Heremans					
invited	C.XIII- 1	30-05-2013	16:30	Impact of electronic correlations on the transport in transition-metal oxides	LECHERMANN	Frank
invited oral	C.XIII- 1 C.XIII- 2	<b>30-05-2013</b> 30-05-2013	16:30 17:00	Impact of electronic correlations on the transport in transition-metal oxides Micro-Meter-Scale Molecular Dynamics Simulation of the Lattice Thermal Conductivity of Graphene	LECHERMANN	Frank Yong-Sung
invited oral oral	C.XIII- 1 C.XIII- 2 C.XIII- 3	30-05-2013 30-05-2013 30-05-2013	16:30 17:00 17:15	Impact of electronic correlations on the transport in transition-metal oxides Micro-Meter-Scale Molecular Dynamics Simulation of the Lattice Thermal Conductivity of Graphene Modelling Thermoelectric Materials from First Principles	LECHERMANN KIM MURPHY ARMANDO	Frank Yong-Sung Felipe
invited oral oral oral	C.XIII- 1 C.XIII- 2 C.XIII- 3 C.XIII- 4	30-05-2013 30-05-2013 30-05-2013 30-05-2013	16:30 17:00 17:15 17:30	Impact of electronic correlations on the transport in transition-metal oxides Micro-Meter-Scale Molecular Dynamics Simulation of the Lattice Thermal Conductivity of Graphene Modelling Thermoelectric Materials from First Principles First-principle simulation of Ce and Yb filled superstructures of skutterudites	LECHERMANN KIM MURPHY ARMANDO XIONG for POKROPIVNY	Frank Yong-Sung Felipe Alex
invited oral oral oral oral	C.XIII- 1 C.XIII- 2 C.XIII- 3 C.XIII- 4 C.XIII- 5	30-05-2013 30-05-2013 30-05-2013 30-05-2013 30-05-2013	16:30 17:00 17:15 17:30 17:45	Impact of electronic correlations on the transport in transition-metal oxides Micro-Meter-Scale Molecular Dynamics Simulation of the Lattice Thermal Conductivity of Graphene Modelling Thermoelectric Materials from First Principles First-principle simulation of Ce and Yb filled superstructures of skutterudites Thermoelectric properties of Ni and Sn doped ZnO: A first principle study <b>NOT PRESENTED</b>	LECHERMANN KIM MURPHY ARMANDO XIONG for POKROPIVNY XIONG	Frank Yong-Sung Felipe Alex Shiyun
invited oral oral oral oral	C.XIII- 2 C.XIII- 3 C.XIII- 4 C.XIII- 5 C.XIII- 5 C.XIII- 6	30-05-2013 30-05-2013 30-05-2013 30-05-2013 30-05-2013 30-05-2013	16:30 17:00 17:15 17:30 17:45 18:00	Impact of electronic correlations on the transport in transition-metal oxides Micro-Meter-Scale Molecular Dynamics Simulation of the Lattice Thermal Conductivity of Graphene Modelling Thermoelectric Materials from First Principles First-principle simulation of Ce and Yb filled superstructures of skutterudites Thermoelectric properties of Ni and Sn doped ZnO: A first principle study <b>NOT PRESENTED</b> Strongly enhanced thermal transport in a lightly doped Mott insulator- <b>REMOVED</b>	LECHERMANN KIM MURPHY ARMANDO XIONG for POKROPIVNY XIONG	Frank Yong-Sung Felipe Alex Shiyun Veljko